LF353 JFET-INPUT DUAL OPERATIONAL AMPLIFIER SLOS012B – MARCH 1987 – REVISED AUGUST 1994

- Low Input Bias Current . . . 50 pA Typ
- Low Input Noise Current 0.01 pA/√Hz Typ
- Low Input Noise Voltage . . . 18 nV/\Hz Typ
- Low Supply Current . . . 3.6 mA Typ
- High Input Impedance . . . $10^{12} \Omega$ Typ
- Internally Trimmed Offset Voltage
- Gain Bandwidth . . . 3 MHz Typ
- High Slew Rate ... 13 V/μs Typ

description

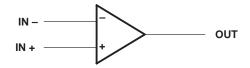
D OR P PACKAGE (TOP VIEW) 10UT Vcc+ 8 20UT 1IN-7 Ш 2 6 2IN-1IN+ [3 12IN+ 4 5 Vcc

This device is a low-cost, high-speed, JFET-input operational amplifier with very low input offset voltage. It requires low supply current yet maintains a large gain-bandwidth product and a fast slew rate. In addition, the matched high-voltage JFET input provides very low input bias and offset currents.

The LF353 can be used in applications such as high-speed integrators, digital-to-analog converters, sample-and-hold circuits, and many other circuits.

The LF353 is characterized for operation from 0°C to 70°C.

symbol (each amplifier



AVAILABLE OPTIONS

T _A	Viemox	PACKAGE		
	V _{IO} max AT 25°C	SMALL OUTLINE (D)	PLASTIC DIP (P)	
0°C to 70°C	10 mV	LF353D	LF353P	

The D packages are available taped and reeled. Add the suffix R to the device type (ie., LF353DR).

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC +}	
Supply voltage, V _{CC -}	18 V
Differential input voltage, VID	±30 V
Input voltage, V _I (see Note 1)	±15 V
Duration of output short circuit	unlimited
Continuous total power dissipation	500 mW
Operating temperature range	0°C to 70°C
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: Unless otherwise specified, the absolute maximum negative input voltage is equal to the negative power supply voltage.



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recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V _{CC +}	3.5	18	V
Supply voltage, V _{CC –}	-3.5	-18	V

electrical characteristics over operating free-air temperature range, $V_{CC\pm}$ = ±15 V (unless otherwise specified)

	PARAMETER	TEST CO	NDITIONS	T _A †	MIN	TYP	MAX	UNIT
Vio		V/ 0		25°C		5	10	mV
VIO	Input offset voltage	$V_{IC} = 0,$	R _S = 10 kΩ	Full range			13	
αγιο	Average temperature coefficient of input offset voltage	V _{IC} = 0,	R _S = 10 kΩ			10		μV/°C
li o	1	$\lambda = 0$		25°C		25	100	pА
IIO	Input offset current‡	$\Lambda^{IC} = 0$		70°C			4	nA
lun.	Input bias current [‡]	VIC = 0		25°C		50	200	pА
IВ				70°C			8	nA
VICR	Common-mode input voltage range				±11	-12 to 15		V
VOM	Maximum peak output voltage swing	$R_L = 10 \ k\Omega$			±12	±13.5		V
A		$\gamma = \pm 10 \gamma$	$\mathbf{P}_{\mathbf{k}} = 2 \mathbf{k} 0$	25°C	25	100		V/mV
AVD	Large-signal differential voltage	$V_{O} = \pm 10 V,$	$R_L = 2 k\Omega$	Full range	15			
ri	Input resistance	T _J = 25°C				10 ¹²		Ω
CMRR	Common-mode rejection ratio	$R_S \le 10 \ k\Omega$			70	100		dB
ksvr	Supply-voltage rejection ratio	See Note 2			70	100		dB
ICC	Supply current					3.6	6.5	mA

[†]Full range is 0°C to 70°C.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperatures as close to the ambient temperature as possible.

NOTE 2: Supply-voltage rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously.

operating characteristics, V_{CC\pm} = ± 15 V, T_A = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V ₀₁ /V ₀₂	Crosstalk attentuation	f = 1 kHz		120		dB
SR	Slew rate		8	13		V/µs
B ₁	Unity-gain bandwidth			3		MHz
V _n	Equivalent input noise voltage	f = 1 kHz, $R_S = 20 \Omega$		18		nV/√Hz
I _n	Equivalent input noise current	f = 1 kHz		0.01		pA/√Hz



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